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FGH30T65UPDT

650V, 30A Field Stop Trench IGBT

Features

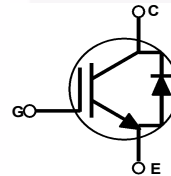
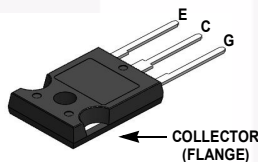
- Maximum Junction Temperature : $T_J = 175^{\circ}\text{C}$
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.65\text{ V (Typ.) @ } I_C = 30\text{ A}$
- 100% of Parts Tested $I_{LM(2)}$
- High Input Impedance
- Tightened Parameter Distribution
- RoHS Compliant
- Short Circuit Ruggedness $> 5\text{ us @ } 25^{\circ}\text{C}$

General Description

Using novel field stop trench IGBT technology, Fairchild's new series of field stop trench IGBTs offer the optimum performance for solar inverter, UPS and digital power generator where low conduction and switching losses are essential.

Applications

- Solar Inverter, UPS, Digital Power Generator



Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
V_{CES}	Collector to Emitter Voltage	650	V
V_{GES}	Gate to Emitter Voltage	± 20	V
	Transient Gate to Emitter Voltage	± 25	V
I_C	Collector Current @ $T_C = 25^{\circ}\text{C}$	60	A
	Collector Current @ $T_C = 100^{\circ}\text{C}$	30	A
$I_{CM(1)}$	Pulsed Collector Current	90	A
$I_{LM(2)}$	Clamped Inductive Load Current	90	A
I_F	Diode Forward Current @ $T_C = 25^{\circ}\text{C}$	60	A
	Diode Forward Current @ $T_C = 100^{\circ}\text{C}$	30	A
$I_{FM(1)}$	Pulsed Diode Maximum Forward Current	150	A
P_D	Maximum Power Dissipation @ $T_C = 25^{\circ}\text{C}$	250	W
	Maximum Power Dissipation @ $T_C = 100^{\circ}\text{C}$	125	W
SCWT	Short Circuit Withstand Time @ $T_C = 25^{\circ}\text{C}$	5	us
T_J	Operating Junction Temperature	-55 to +175	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	-55 to +175	$^{\circ}\text{C}$
T_L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^{\circ}\text{C}$

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

2: $I_C = 90\text{ A}$, $V_{CC} = 400\text{ V}$, $R_g = 20\ \Omega$

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case	-	0.60	$^{\circ}\text{C/W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case	-	1.2	$^{\circ}\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	$^{\circ}\text{C/W}$

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH30T65UPD_F155	FGH30T65UPD	TO-247 G03	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_J}$	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 250 uA	-	0.65	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0 V	-	-	±400	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 30 mA, V _{CE} = V _{GE}	4.0	6.0	7.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 30 A, V _{GE} = 15 V	-	1.65	2.3	V
		I _C = 30 A, V _{GE} = 15 V, T _C = 175°C	-	2.1	-	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	-	2280	-	pF
C _{oes}	Output Capacitance		-	85	-	pF
C _{res}	Reverse Transfer Capacitance		-	40	-	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 30 A, R _G = 8 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25°C	-	22	-	ns
t _r	Rise Time		-	26	-	ns
t _{d(off)}	Turn-Off Delay Time		-	139	-	ns
t _f	Fall Time		-	18	-	ns
E _{on}	Turn-On Switching Loss		-	0.76	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.40	-	mJ
E _{ts}	Total Switching Loss	-	1.16	-	mJ	
t _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 30 A, R _G = 8 Ω, V _{GE} = 15V, Inductive Load, T _C = 175°C	-	22	-	ns
t _r	Rise Time		-	30	-	ns
t _{d(off)}	Turn-Off Delay Time		-	151	-	ns
t _f	Fall Time		-	19	-	ns
E _{on}	Turn-On Switching Loss		-	1.20	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.53	-	mJ
E _{ts}	Total Switching Loss	-	1.73	-	mJ	
T _{sc}	Short Circuit Withstand Time	V _{GE} = 15 V, V _{CC} ≤ 400 V, R _g = 10 Ω	5	-	-	us
Q _g	Total Gate Charge	V _{CE} = 400 V, I _C = 30 A, V _{GE} = 15 V	-	155	-	nC
Q _{ge}	Gate to Emitter Charge		-	21	-	nC
Q _{gc}	Gate to Collector Charge		-	91	-	nC

Electrical Characteristics of the Diode $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max	Unit
V _{FM}	Diode Forward Voltage	I _F = 30 A	T _C = 25°C	-	2.3	3.0	V
			T _C = 175°C	-	1.9	-	
E _{rec}	Reverse Recovery Energy	I _F = 30 A, di _F /dt = 200 A/μs	T _C = 175°C	-	35	-	μJ
t _{rr}	Diode Reverse Recovery Time		T _C = 25°C	-	33	43	ns
			T _C = 175°C	-	148		
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	-	57	80	nC
			T _C = 175°C	-	560		

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

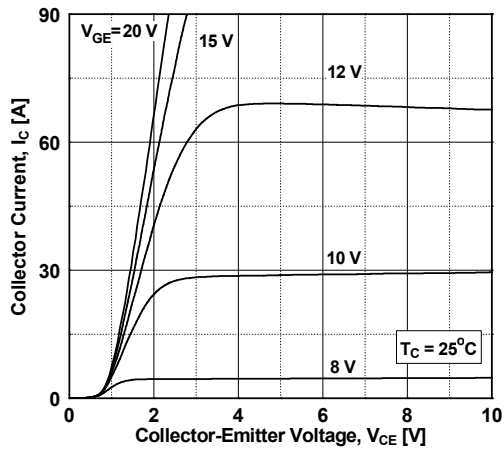


Figure 2. Typical Output Characteristics

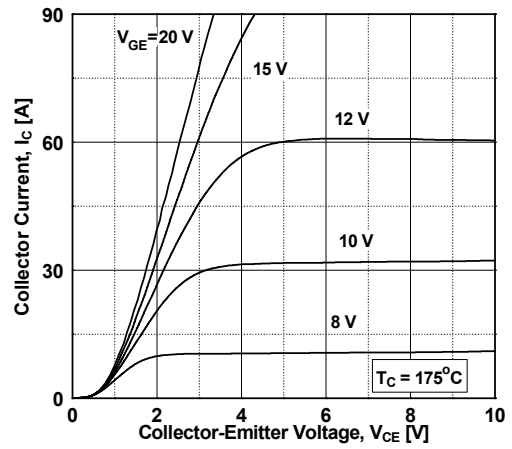


Figure 3. Typical Saturation Voltage Characteristics

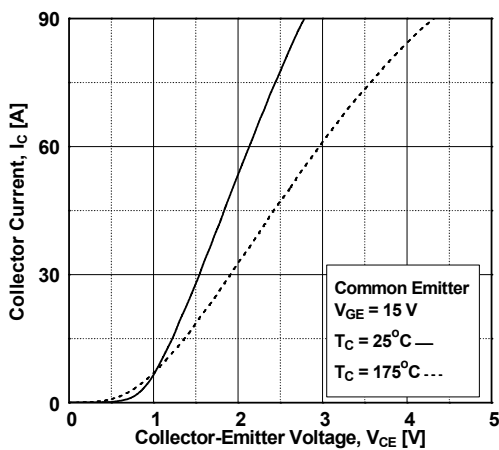


Figure 4. Saturation Voltage vs. Case Temperature at Variant Current Level

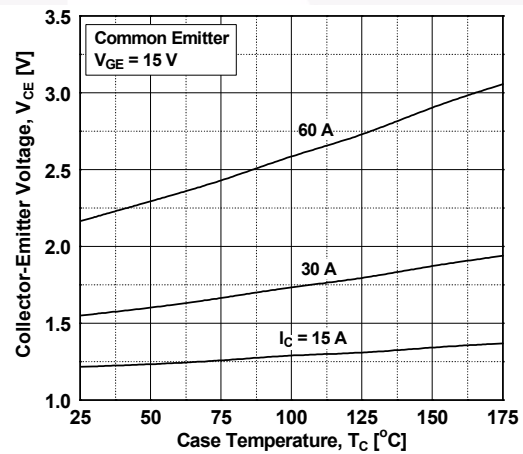


Figure 5. Saturation Voltage vs. V_{GE}

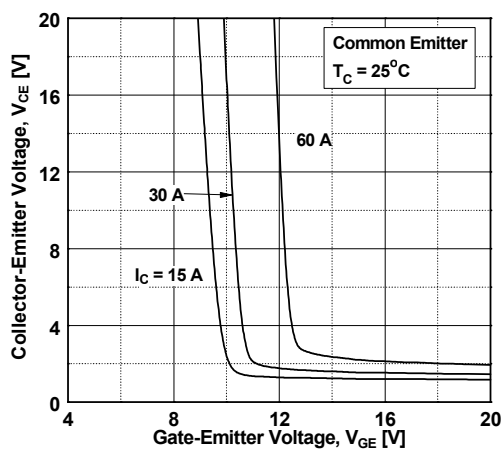
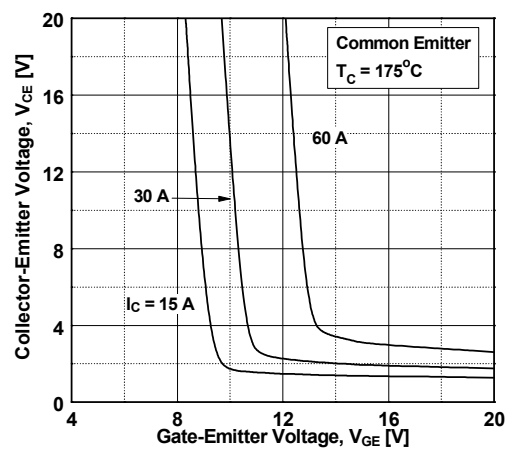


Figure 6. Saturation Voltage vs. V_{GE}



Typical Performance Characteristics

Figure 7. Capacitance Characteristic

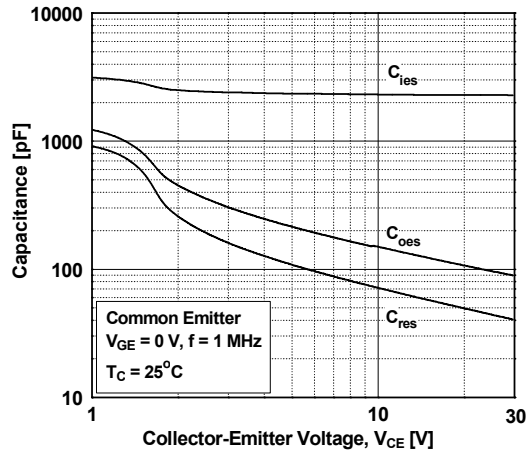


Figure 8. Gate charge Characteristics

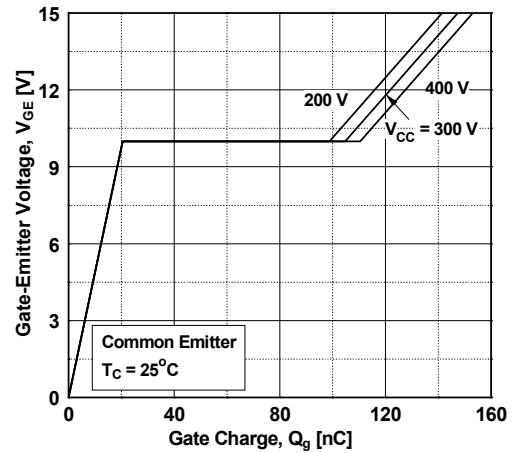


Figure 9. Turn-on Characteristics vs. Gate Resistance

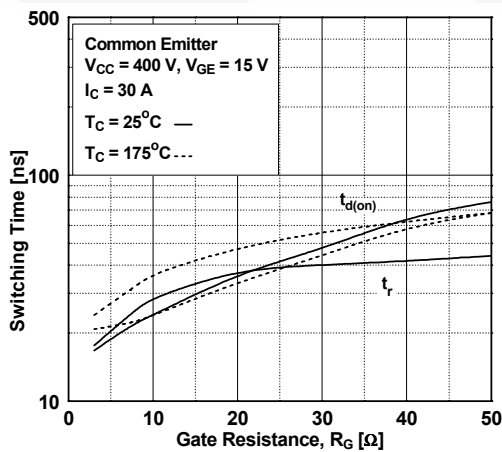


Figure 10. Turn-off Characteristics vs. Gate Resistance

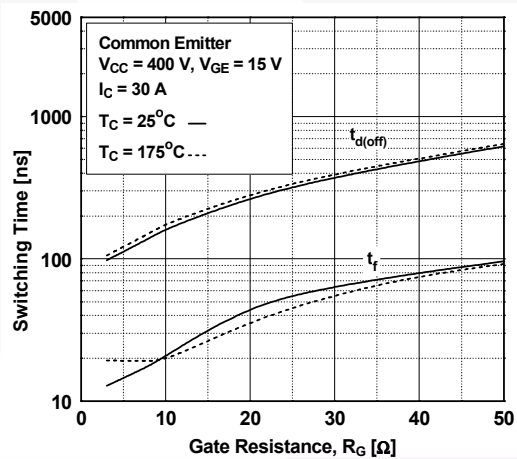


Figure 11. Switching Loss vs. Gate Resistance

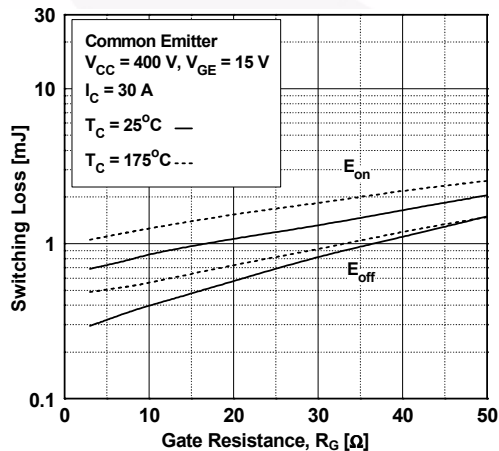
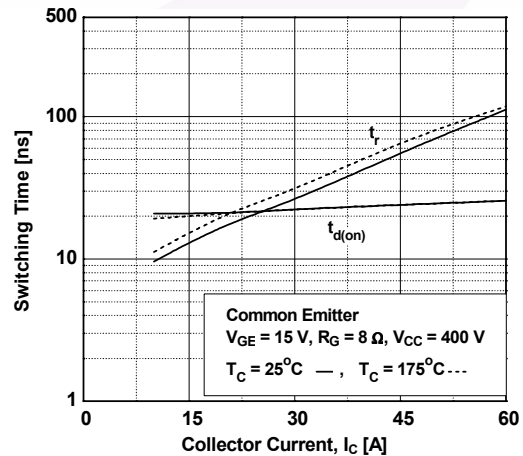


Figure 12. Turn-on Characteristics vs. Collector Current



Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

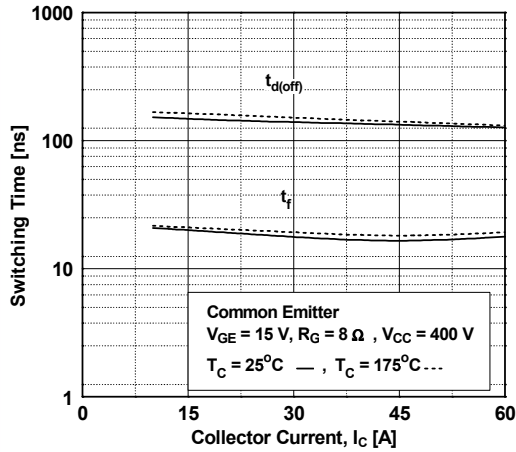


Figure 14. Switching Loss vs. Collector Current

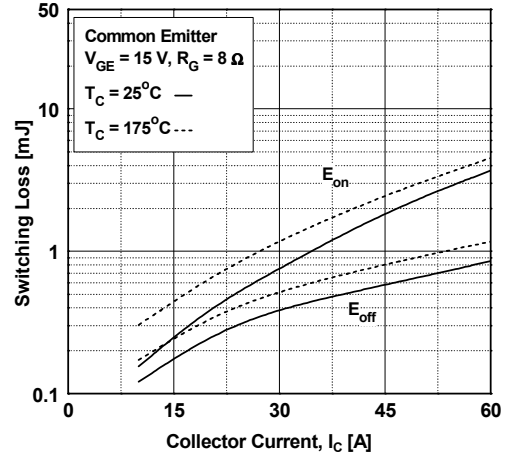


Figure 15. Load Current vs. Frequency

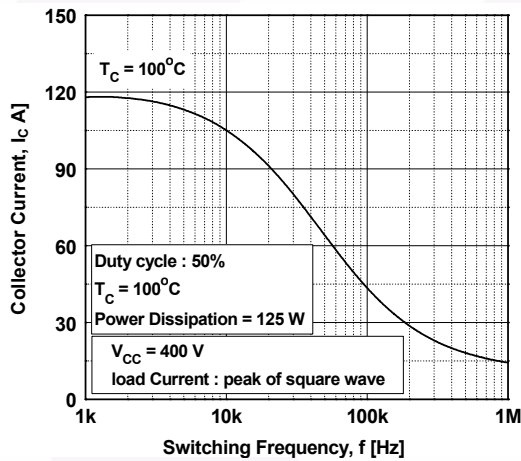


Figure 16. SOA Characteristics

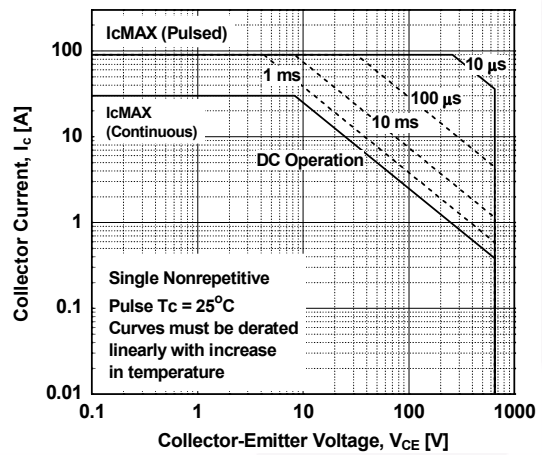


Figure 17. Forward Characteristics

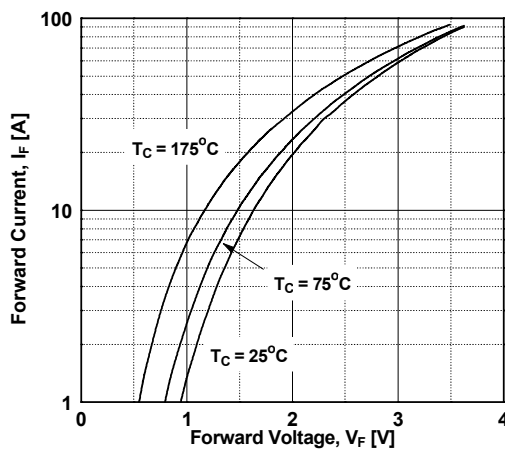
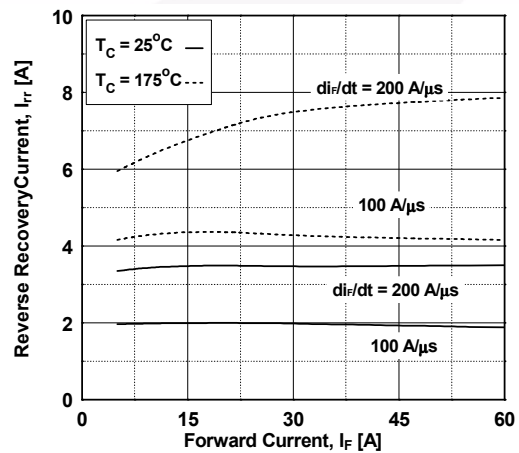


Figure 18. Reverse Recovery Current



Typical Performance Characteristics

Figure 19. Reverse Recovery Time

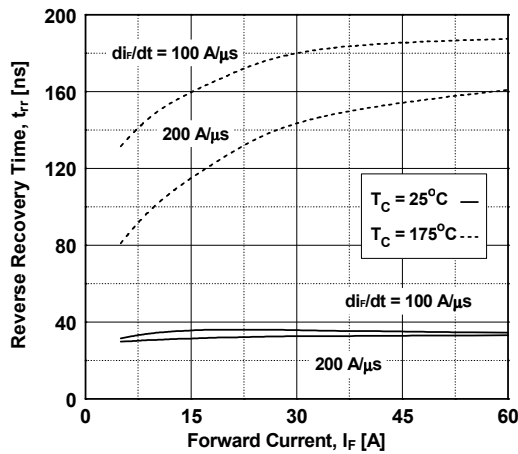


Figure 20. Stored Charge

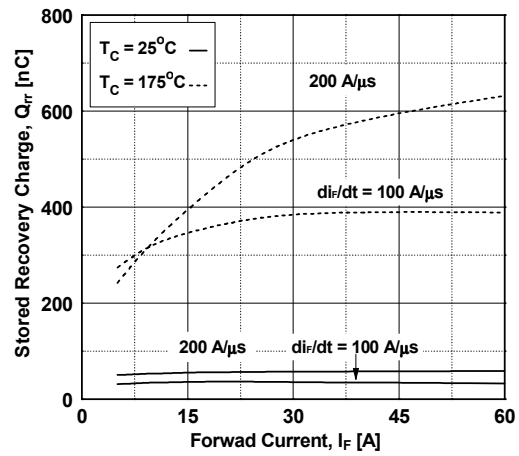


Figure 21. Transient Thermal Impedance of IGBT

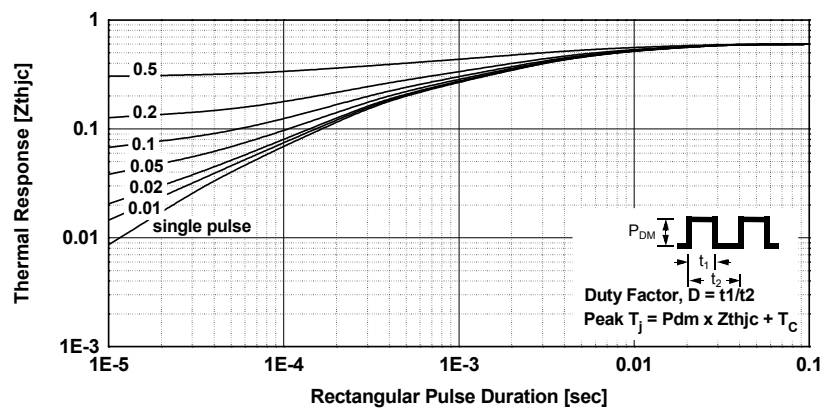
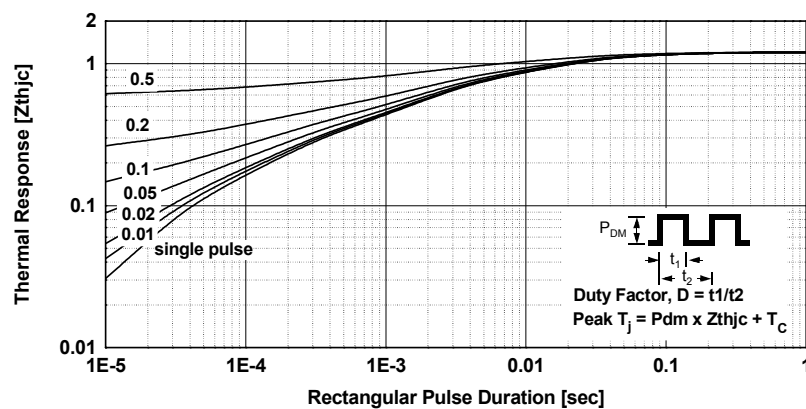
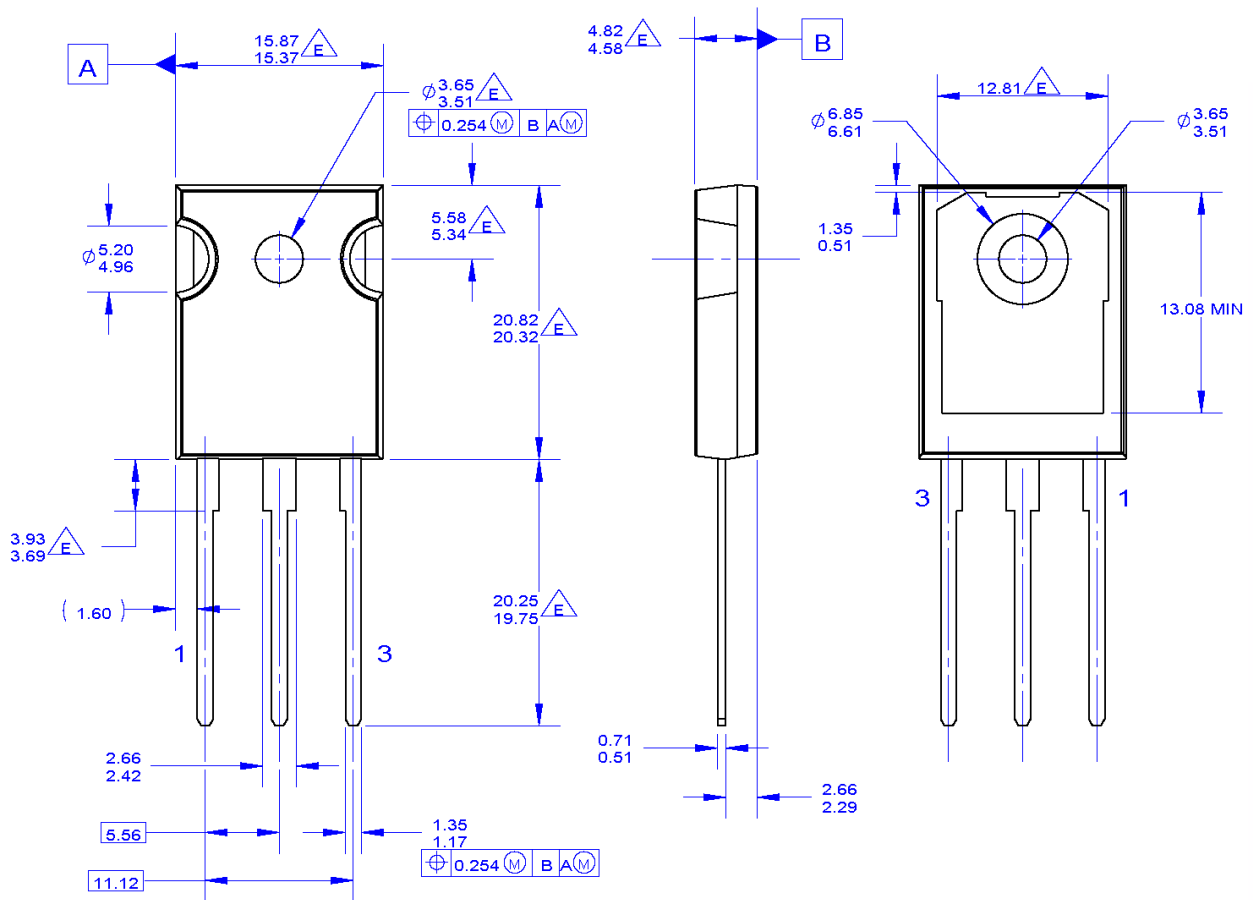


Figure 22. Transient Thermal Impedance of Diode



Mechanical Dimensions



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- D. DRAWING CONFORMS TO ASME Y14.5 - 1994

E. DOES NOT COMPLY JEDEC STANDARD VALUE
F. DRAWING FILENAME: MKT-TO247G03_REV01

Figure 23. TO247, Molded, 3-Lead, JEDEC AB Long Lead

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Dimensions in Millimeters



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- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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